# Onsemi

# Silicon Carbide (SiC) **Schottky Diode** – EliteSiC, 16 A, 650 V, D1, TO-247-2L

# **FFSH1665A**

#### Description

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

- Max Junction Temperature 175°C
- Avalanche Rated 81 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- This Device is Pb-Free and is RoHS Compliant

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of

### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C, Unless otherwise specified)

Symbol	Parameter		FFSH1665A	Unit
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage		650	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)		81	mJ
١ <sub>F</sub>	Continuous Rectified Forward Current	@ Tc < 152°C	16	А
		@ Tc < 135°C	23	
I <sub>F, Max</sub>	Non-Repetitive Peak Forward Surge Current	Tc = 25°C, 10 μs	1000	A
		Tc = 150°C, 10 μs	900	А
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, tp = 8.3 ms	90	А
I <sub>F, RM</sub>	Repetitive Forward Surge Current	Half-Sine Pulse, tp = 8.3 ms	50	А
P <sub>tot</sub>	Power Dissipation	Tc = 25°C	161	W
		Tc = 150°C	27	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	_∕°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1.  $E_{AS}$  of 81 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 18$  A, V = 50 V. END

#### **THERMAL CHARACTERISTICS**

Symbol	Parameter		Rating	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.		0.93	°C/W	
PACKAGE MARKING AND ORDERING INFORMATION					

# PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking Package	Shipping
FFSH1665A	FFSH1665A TO-247-2LD	30 Units / Tube

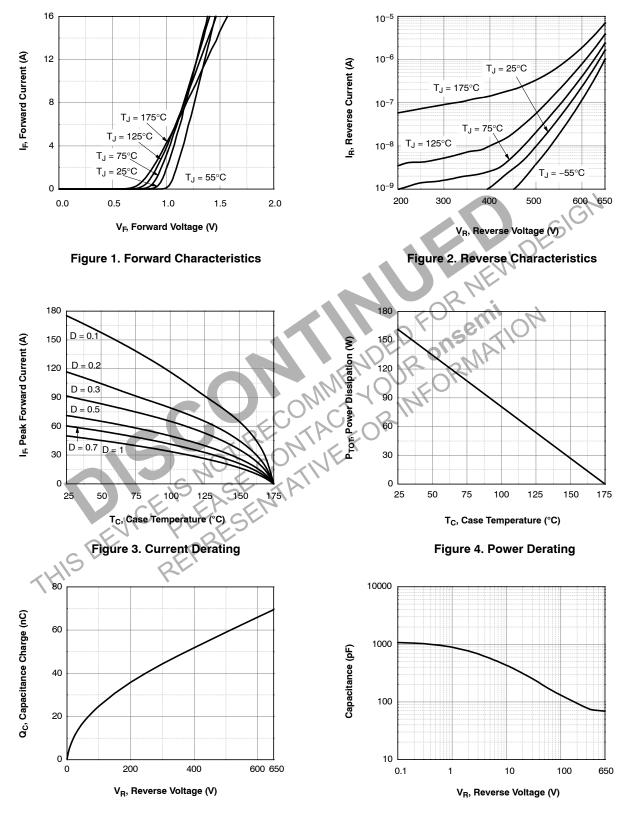
# ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	l⊧ = 16 A, Tc = 25°C	-	1.50	1.75	V
	- 15 ASL	IF = 16 A, Tc = 125°C	-	1.6	2.0	
	INCE LE SE	I⊧ = 16 A, Tc = 175°C	-	1.72	2.4	
I <sub>R</sub>	Reverse Current	VR = 650 V, Tc = 25°C	-	-	200	μA
	SV SEP	VR = 650 V, Tc = 125°C	-	-	400	
14	C Kr	VR = 650 V, Tc = 175°C	-	-	600	
Q <sub>C</sub>	Total Capacitive Charge	V = 400 V	-	52	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	887	-	pF
		V <sub>R</sub> = 200 V, f = 100 kHz	-	95	-	
		VR = 400 V, f = 100 kHz	-	72	-	

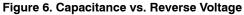
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **TYPICAL CHARACTERISTICS**

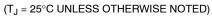
 $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED})$ 

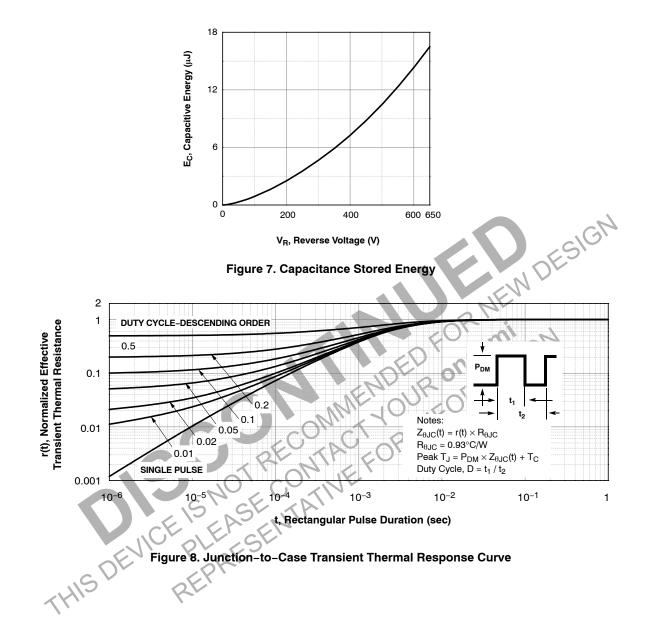




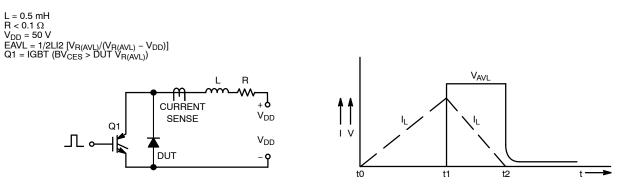


# TYPICAL CHARACTERISTICS (CONTINUED)





### **TEST CIRCUIT AND WAVEFORMS**





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**MILLIMETERS** 

NOM

4.70

2.40

1.50

1.26

1.65

0.61

20.57

16.57

0.93

15.62

~

5.08

11.12

16.00

3.81

3.58

6.73

5.46

5.46

MAX

4.82

2.66

1.70

1.35

1.77

0.71

20.82

16.77

1.35

15.87

~

5.20

~

16.25

3.93

3.65

6.85

5.58

5.58

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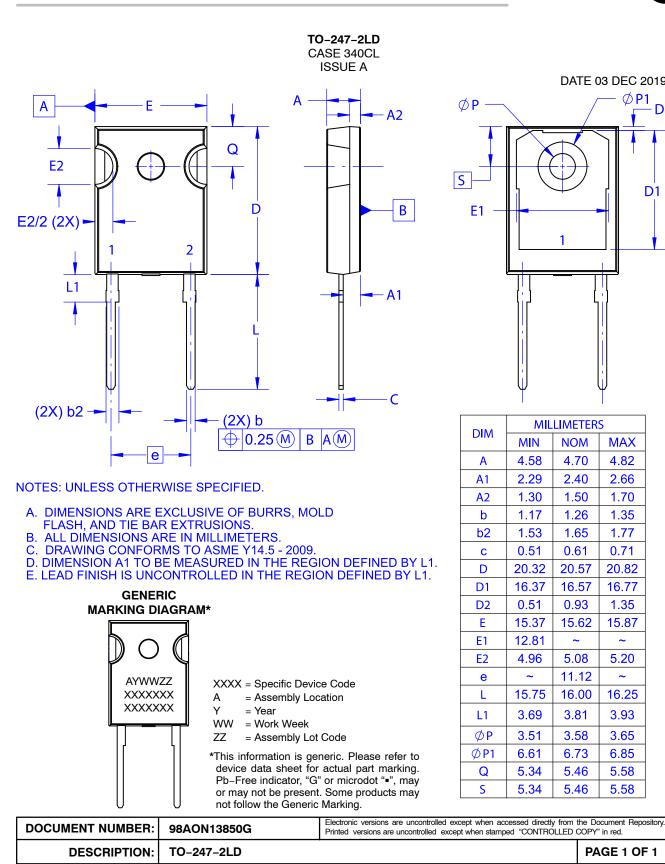
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ØP1



D2

D1



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